

Intro to ECSE Class 11: Diodes and Differential Resistance 1

I Overview of Lab 02: Parts A & B

1. Introduce the concept of **linearity**
2. Give you another tool for solving and designing circuits: **nodal analysis**
3. Provide an example of non-linearity: **diodes**

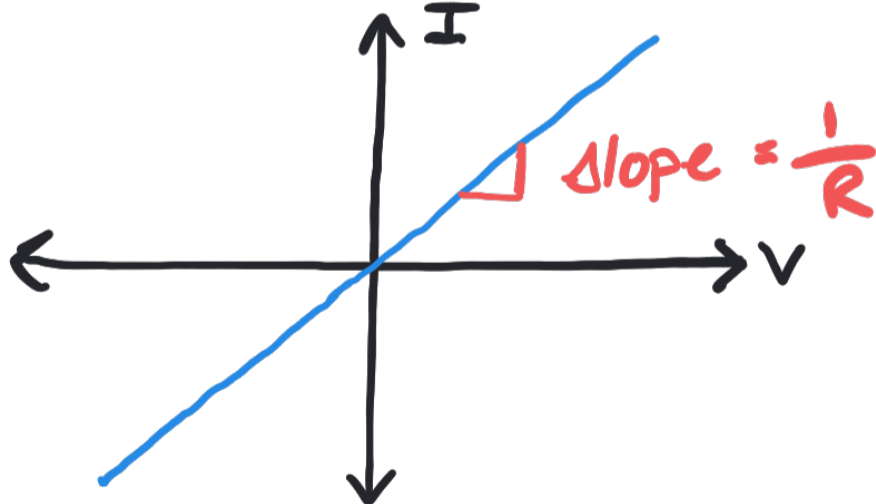
Part A: Defining Linear & Non-Linear Device IV Characteristics (**today**)

Part B: Solving Linear Resistive Networks Using Nodal Analysis

II Linear and Non-Linear IV Characteristics

1. Resistor

- IV characteristic



$$\begin{aligned} V &= IR \\ \Delta V &= \Delta I R \end{aligned}$$

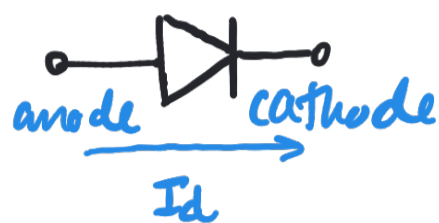
slope: $\frac{\Delta I}{\Delta V} = \frac{1}{R}$

- $V = IR \rightarrow$ straight line \rightarrow linear component

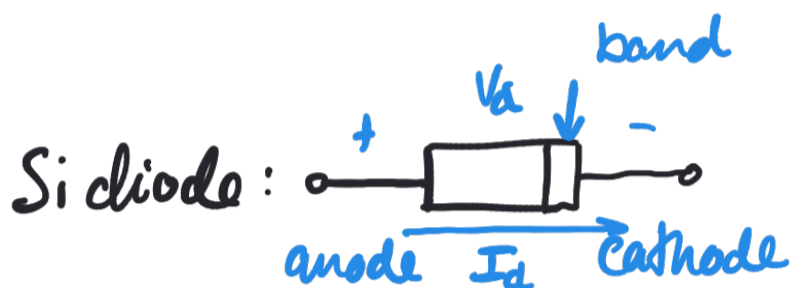
2. Diode : allows current to flow in only one ²

a) Circuit symbol

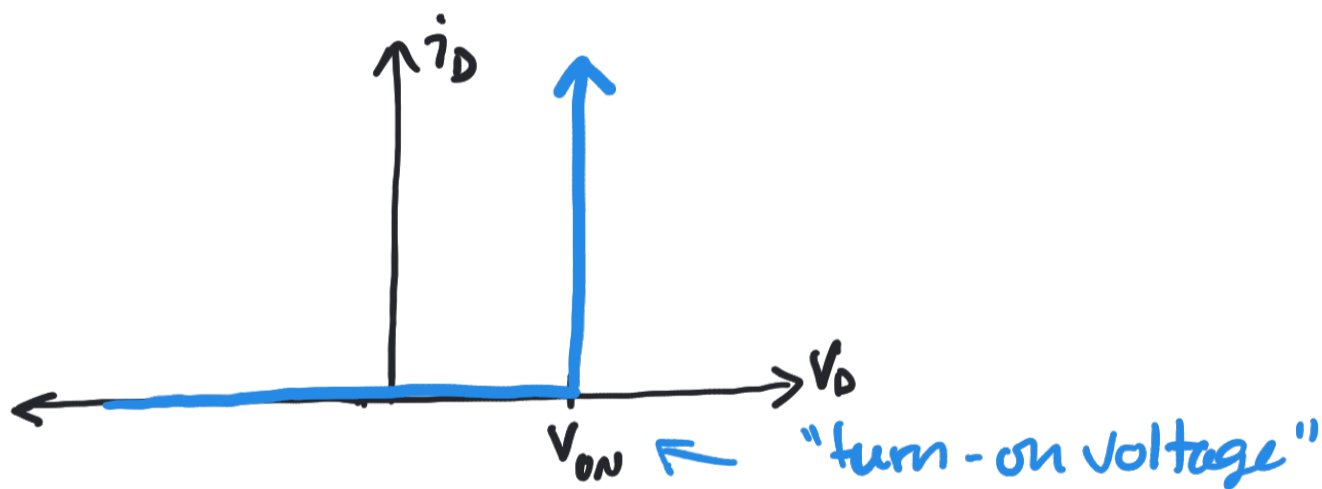
"normal" diode



• actual part appearance



b) Model #1: Simple ideal diode model



$$i_D = \begin{cases} 0 & V_d < V_{on} \\ \infty & V_d \geq V_{on} \end{cases}$$

• Turn-on voltage V_{on} : voltage when current starts to flow

• Typical values of V_{on}

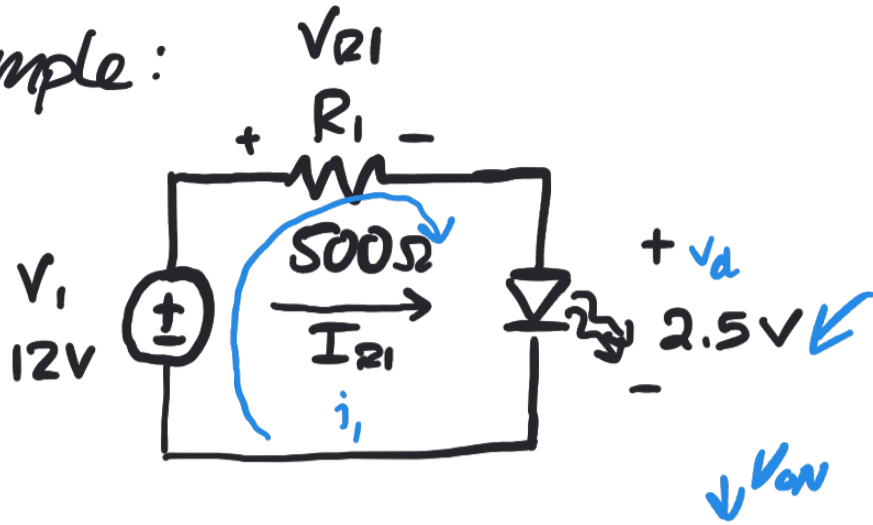
• Si : 0.7V

• LEDs: 1.5V+ → depends on color

• useful for simple analysis of diode circuits

Example:

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• Find V_{R1} and I_{R1}

$V_{ON} = 2.5V$ - fixed regardless of current

• Use KVL: $-12V + V_{R1} + 2.5V = 0 \rightarrow \underline{V_{R1} = 9.5V}$

• Use Ohm's Law: $I_{R1} = \frac{V_{R1}}{R1} = \frac{9.5V}{500\Omega} = \underline{19mA}$

C) The actual ideal diode model

• Differences compared to simple model

• I_d is not infinity for $V_d > V_{ON}$ (resistance of IV curve is not 0)

Current flows in the "wrong" direction

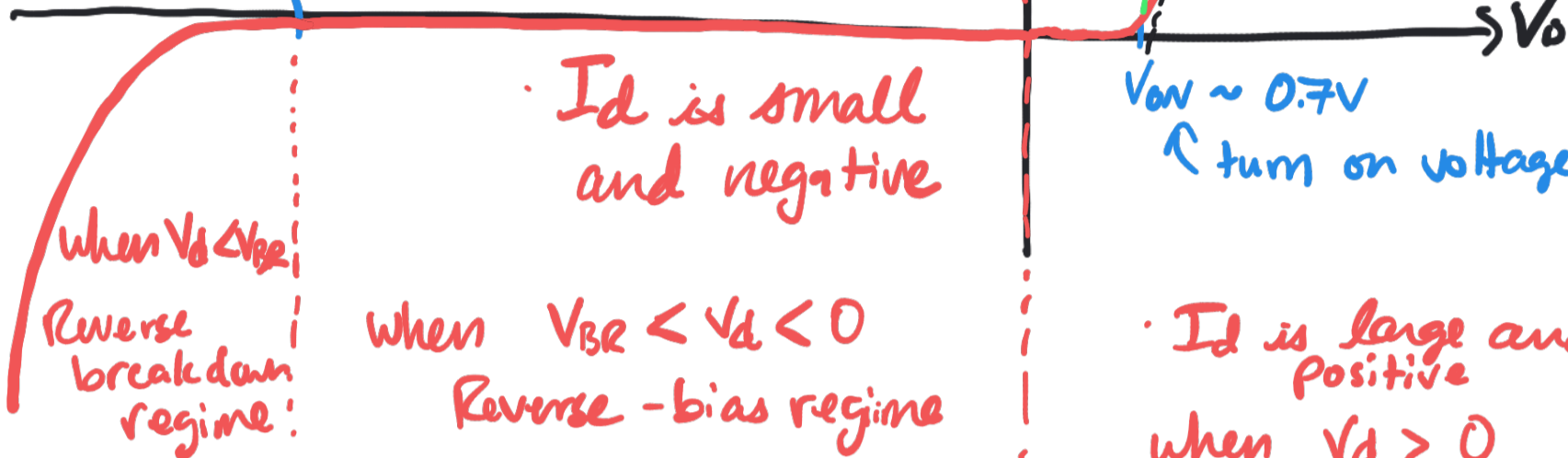
• If $V_d < V_{ON}$, a small negative current flows
↳ I_s : saturation current

• If $V_d < V_{BR}$ (reverse breakdown voltage), a large negative current will flow

IV Characteristic

I_d is large and negative

reverse breakdown voltage
 $V_{BR} \sim -100V$ typically



I_d is small and negative

When $V_{BR} < V_d < 0$
 Reverse-bias regime

I_d is large and positive
 when $V_d \geq 0$

Forward-bias regime

Ideal diode equation:

$$I_d = I_s \left(e^{\frac{qV_d}{n k_B T}} - 1 \right)$$

Annotations for the equation:
 - q : charge of an electron
 - k_B : Boltzmann's constant
 - T : temperature (1 < n < 2 typically)
 - n : ideality factor
 - I_s : saturation current (what flows in reverse bias)

In forward bias $V_d > V_{ON}$
 $I_d \sim I_s e^{\frac{qV_d}{n k_B T}}$

In reverse bias $V_d < 0$
 $I_d \sim -I_s$

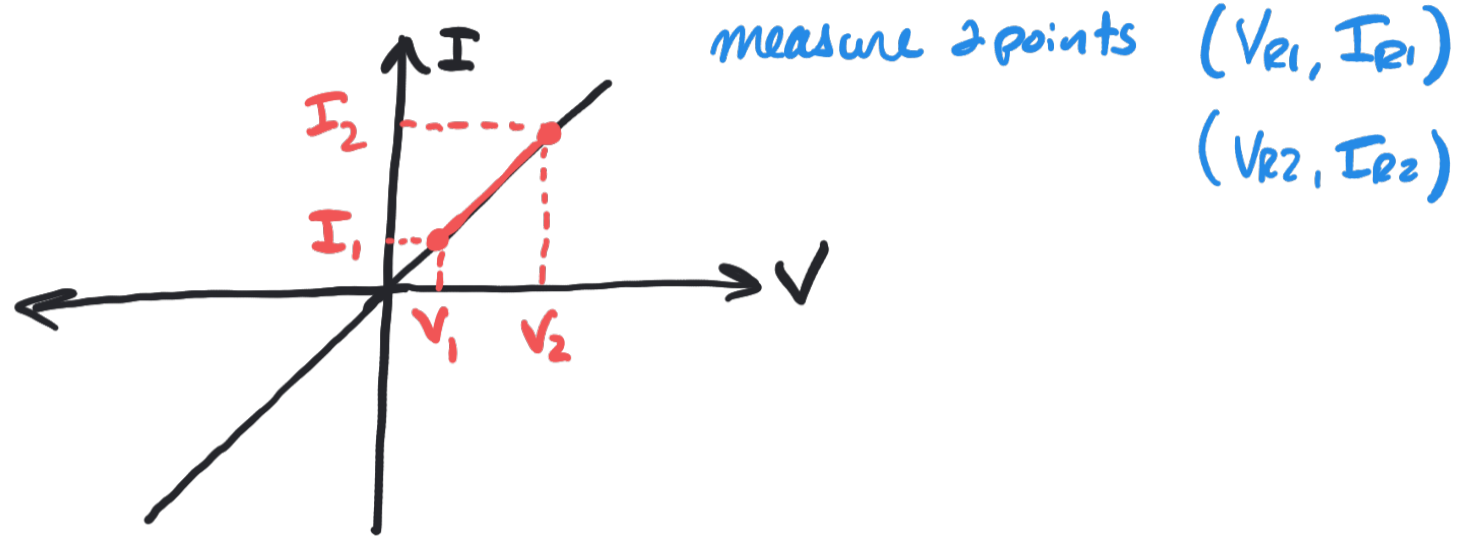
In reverse breakdown: not in equation

3. Differential Resistance

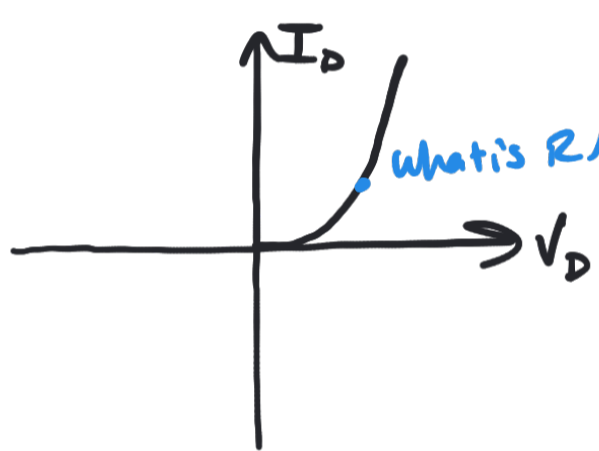
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so far we have defined resistance on an IV characteristic as $R = \frac{\Delta V}{\Delta I}$

or $R = \frac{V_{R2} - V_{R1}}{I_{R2} - I_{R1}} = \frac{\Delta V}{\Delta I}$



But what about non-linear IV Characteristics?



$R = \frac{\Delta V}{\Delta I} \rightarrow \frac{dV}{dI} \Big|_{(V_0, I_0)} = R_{diff}$

We need: calculus \rightarrow relation to slope of IV curve at a point (V_0, I_0)

Differential Resistance: local measure of resistance how much does V change (dV) for a small change in I (dI)

$R_{diff} = \frac{dV}{dI} \Big|_{(V_0, I_0)} \rightarrow V = IR$
 $\frac{d}{dI}(V) = \frac{d}{dI}(IR)$

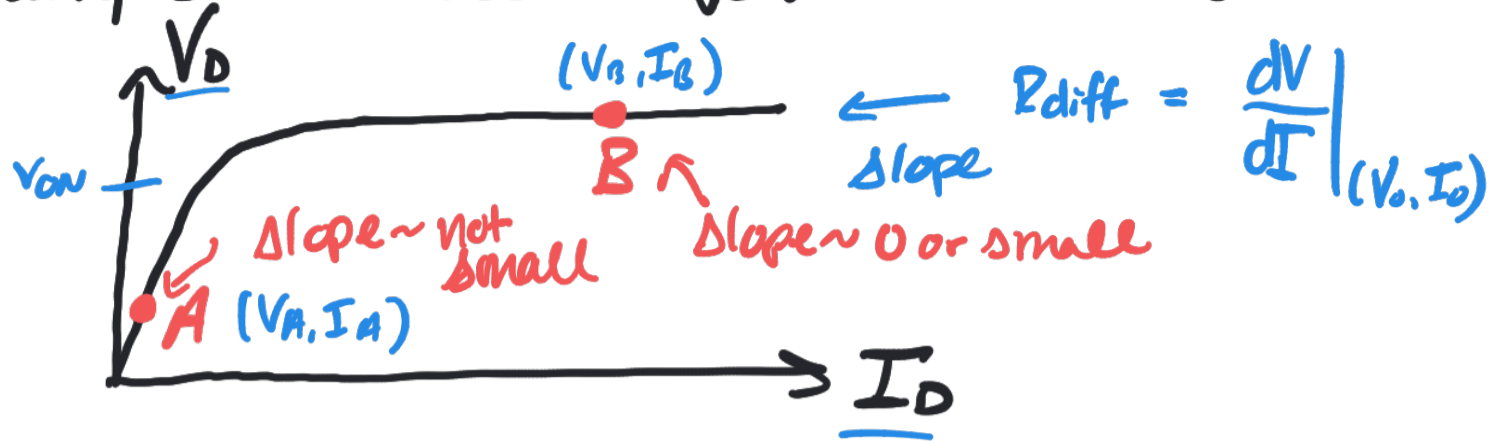
What is "resistance" then?

It's how much V changes for a change in I

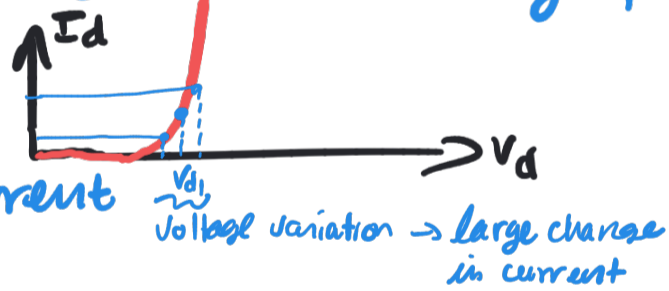
$\frac{dV}{dI} = R$

Example: diode in forward-bias

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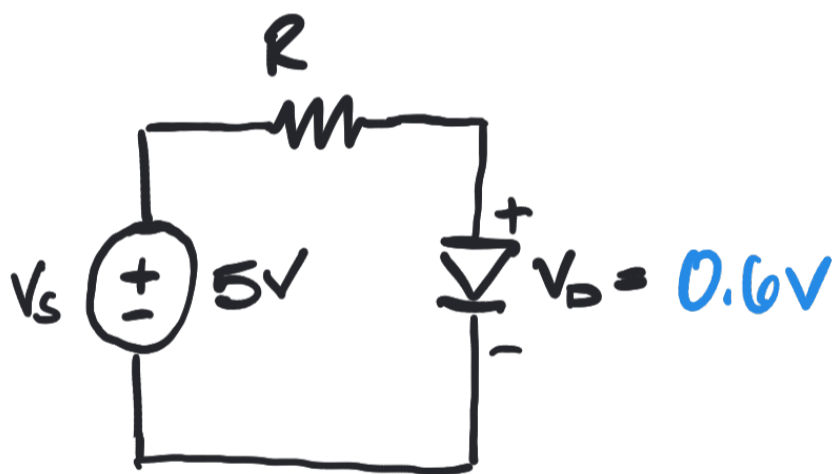
- At which point is R_{diff} smaller?
- R_{diff} for a diode is very small for $V_D > V_{ON}$
small changes in V_D lead to large changes in I_D
- Consequences of varying differential resistance for diodes:
 - Voltage vs. current control: it's difficult to drive a diode at a constant voltage & current using voltage
 - drive a diode with current
 - current limiting:
 - If we give a diode too much current it can break. We should put a resistor in series with the diode to keep the current at a safe level



4. Current-Limiting Resistor

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- Given the max. current & turn-on voltage of a diode, we can choose a resistor to limit the current to a safe value
- How do we find the max. current for a diode?
 - $I_{max} = 300\text{mA}$
 - $V_{on} = 600\text{mV @ } 1\text{mA}$



$$4.4\text{V} = V_R$$

Choose R so that $I_d < 300\text{mA}$

$$\text{say } I_R = 150\text{mA}$$

$$R = \frac{V_R}{I_R} = \frac{4.4\text{V}}{150\text{mA}} = \underline{30\Omega}$$

- What value of R will limit the current to a safe value? for this case $R > 30\Omega$
typically we use $R \sim 100\Omega$